

Vishay General Semiconductor

Surface Mount PAR[®] Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



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DO-218 Compatible

Anode O Cathode

LINKS TO ADDITIONAL RESOURCES





PRIMARY CHARACTERISTICS						
V _{WM}	10 V to 43 V					
V _{BR}	11.1 V to 52.8 V					
P _{PPM} (10 x 1000 μs)	6600 W					
P _{PPM} (10 x 10 000 μs)	5200 W					
PD	8 W					
I _{FSM}	700 A					
T _J max.	175 °C					
Polarity	Unidirectional					
Package	DO-218AC					

FEATURES

- Junction passivation optimized design passivated anisotropic rectifier technology
- T_J = 175 °C capability suitable for high reliability and automotive requirement
- Unidirectional
- Low leakage current
- Low forward voltage drop
- High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified available
 Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lightning, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AC

Molding compound meets UL 94 V-0 flammability rating Base P/NHM3 - RoHS-compliant, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 HM3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)									
PARAMETER		SYMBOL	VALUE	UNIT					
Peak pulse power dissipation	with 10/1000 µs waveform	Р	6600	W					
	with 10/10 000 µs waveform	P _{PPM}	5200	vv					
Power dissipation on infinite heats	sink at T _A = 25 °C (fig. 1)	PD	8.0	W					
Peak pulse current with 10/1000	us waveform	I _{PPM} ⁽¹⁾	See next table	A					
Peak forward surge current 8.3 m	s single half sine-wave	I _{FSM}	700	A					
Operating junction and storage te	mperature range	T _J , T _{STG}	-55 to +175	°C					

Note

⁽¹⁾ Non-repetitive current pulse at $T_A = 25 \ ^{\circ}C$

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RoHS COMPLIANT HALOGEN



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ELECTRICAL CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise noted)										
DEVICE TYPE	BREAKDOWN VOLTAGE V _{BR} (V)			TEST CURRENT	STAND-OFF VOLTAGE	MAXIMUM REVERSE LEAKAGE	MAXIMUM REVERSE LEAKAGE	MAX. PEAK PULSE CURRENT	MAXIMUM CLAMPING VOLTAGE	TYPICAL TEMP. COEFFICIENT
	MIN.	NOM.	MAX.	Ι _Τ (mA)	V _{WM} (V)	ΑΤ V _{WM} Ι _D (μΑ)	AT V _{WM} T _J = 175 °C I _D (μΑ)	AT 10/1000 μs WAVEFORM (A)	AT I _{PPM} V _C (V)	OF V _{BR} ⁽¹⁾ αΤ (%/°C)
SM8S10AHM3	11.1	11.7	12.3	5.0	10.0	15	250	388	17.0	0.069
SM8S11AHM3	12.2	12.9	13.5	5.0	11.0	10	150	363	18.2	0.072
SM8S12AHM3	13.3	14.0	14.7	5.0	12.0	10	150	332	19.9	0.074
SM8S13AHM3	14.4	15.2	15.9	5.0	13.0	10	150	307	21.5	0.076
SM8S14AHM3	15.6	16.4	17.2	5.0	14.0	10	150	284	23.2	0.078
SM8S15AHM3	16.7	17.6	18.5	5.0	15.0	10	150	270	24.4	0.080
SM8S16AHM3	17.8	18.8	19.7	5.0	16.0	10	150	254	26.0	0.081
SM8S17AHM3	18.9	19.9	20.9	5.0	17.0	10	150	239	27.6	0.082
SM8S18AHM3	20.0	21.1	22.1	5.0	18.0	10	150	226	29.2	0.083
SM8S20AHM3	22.2	23.4	24.5	5.0	20.0	10	150	204	32.4	0.085
SM8S22AHM3	24.4	25.7	26.9	5.0	22.0	10	150	186	35.5	0.086
SM8S24AHM3	26.7	28.1	29.5	5.0	24.0	10	150	170	38.9	0.087
SM8S26AHM3	28.9	30.4	31.9	5.0	26.0	10	150	157	42.1	0.088
SM8S28AHM3	31.1	32.8	34.4	5.0	28.0	10	150	145	45.4	0.089
SM8S30AHM3	33.3	35.1	36.8	5.0	30.0	10	150	136	48.4	0.090
SM8S33AHM3	36.7	38.7	40.6	5.0	33.0	10	150	124	53.3	0.091
SM8S36AHM3	40.0	42.1	44.2	5.0	36.0	10	150	114	58.1	0.091
SM8S40AHM3	44.4	46.8	49.1	5.0	40	10	150	102	64.5	0.092
SM8S43AHM3	47.8	50.3	52.8	5.0	43	10	150	95.1	69.4	0.093

Notes

• For all types maximum $V_F = 1.8$ V at $I_F = 100$ A measured on 300 µs square pulse width

⁽¹⁾ To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at T_J = V_{BR} at 25 °C x (1 + α T x (T_J - 25))

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	SYMBOL	VALUE	UNIT					
Tunical thormal registrance	R _{0JA} ⁽¹⁾	55	°C/W					
Typical thermal resistance	R _{0JM} ⁽²⁾	0.35	°C/W					

Notes

⁽¹⁾ Thermal resistance junction-to-ambient to follow JEDEC[®]51-2A, device mounted on FR4 PCB, 2 oz. standard footprint

(2) Thermal resistance junction-to-mount to follow JEDEC®51-14 using Transient Dual Interface Test Method (TDIM)



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ORDERING INFORMATION TABLE

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Device code	SM	x	S	xx	Α	н	М3
		(2)	(3)	(4)	(5)	(6)	(7)
	1	- Sur	face mo	ount	\bigcirc	\bigcirc	\bigcirc
	2	- Pov	ver dissi	ipation F	P _D (5 = 5	5 W, 6 =	6 W, 8
	3	- Sta	ndard V	F type			
	4	- Sta	nd-off v	oltage			
	5	- Bre	akdown	voltage	toleran	ce and p	olarity
	6	- Qua	ality grad	de (H =	AEC-Q1	01 qual	ified, ot
	7				ient cate nd termi	0,0	

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
SM8S10AHM3/I ⁽¹⁾	2.605		750	13" diameter plastic tape and reel, anode towards the sprocket hole				

Note

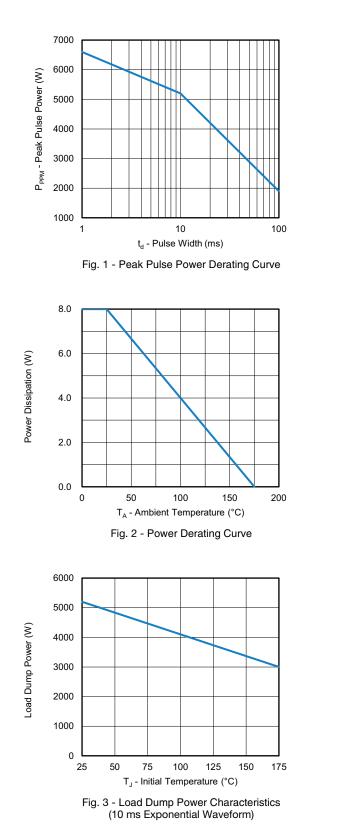
(1) AEC-Q101 qualified



SM8S10AHM3 thru SM8S43AHM3

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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)



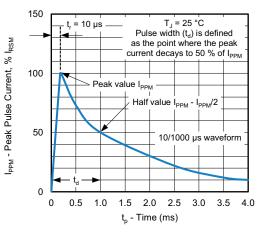


Fig. 4 - Pulse waveform

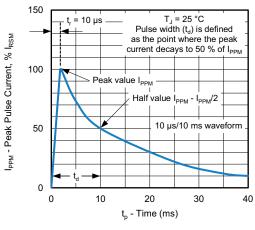


Fig. 5 - Pulse Waveform

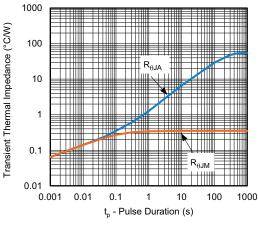


Fig. 6 - Typical Transient Thermal Impedance

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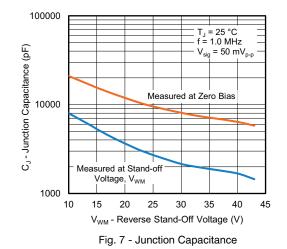
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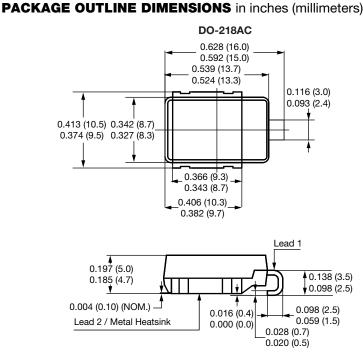
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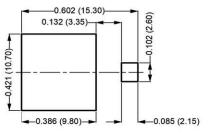
SM8S10AHM3 thru SM8S43AHM3

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Mounting Pad Layout



Note

· Footprint in accordance with IPC 7351 standard

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